



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL31A105KB9LNNC

Product : Multi-layer Ceramic Capacitor
Descriptiont : CAP, 1μF, 50V, ±10%, X5R, 1206

A. Samsung Part Number

<u>CL</u> <u>31</u> <u>A</u> <u>105</u> <u>K</u> <u>B</u> <u>9</u> <u>L</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor								
2	Size	1206 (inch c	ode) L:	3.2	± 0.2	mm	W:	1.6 ± 0.2	mm	
				8	Thickn	ess divisio	n	Low profile		
3	Dielectric	X5R			Inner e	electrode		Ni		
4	Capacitance	1 μF			Termin	nation		Cu		
(5)	Capacitance	±10 %			Plating	J		Sn 100%	(Pb Free)	
	tolerance			9	Produc	ct		Normal		
6	Rated Voltage	50 V		10	Specia	ıl		Reserved for	future use	
7	Thickness	0.9 ± 0.1	mm	11)	Packag	ging		Cardboard T	ype, 7" reel	

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms					
Tan δ (DF)	0.1 max.						
Insulation	10,000Mohm or 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.					
Resistance	Whichever is Smaller						
Appearance	No abnormal exterior appearance	Microscope (×10)					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X5R						
Characterisitcs	(From -55℃ to 85℃, Capacitance change shoud be within ±15%)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120°C for 10~30sec.)					
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance		Test condition
Vibration Test	Capacitance change: within ±	5%	Amplitude: 1.5mm
	Tan δ, IR : initial spec.		From 10Hz to 55Hz (return : 1min.)
			2hours \times 3 direction (x, y, z)
Moisture	Capacitance change : within ±	12.5%	With rated voltage
Resistance	Tan δ: 0.125 max		40±2℃, 90~95%RH, 500+12/-0hrs
	IR : 12.5MΩ·μF or Over		
High Temperature	Capacitance change: within ±	12.5%	With 150% of the rated voltage
Resistance	Tan δ: 0.125 max		Max. operating temperature
	IR: 25MΩ·μF or Over		
			1000+24/-0hrs
Temperature	Capacitance change: within ±	7.5%	1 cycle condition
Cycling	Tan δ, IR : initial spec.		Min. operating temperature → 25°C
			→ Max. operating temperature → 25 °C
			5 cycle test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}\!\!\mathrm{C}$, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.